

(Foreign associate use only)
DECLARATION AND POWER OF ATTORNEY

Attorney's Docket No. 44471-265522 (13700)

As a below named inventor, I hereby declare that:

My residence, post office address, and citizenship are as stated be inventor (if only one name is listed below) or an original, first an	
matter which is claimed and for which a patent is sought on the inv	vention entitled: LATERAL TRANSISTOR HAVING GRADED BASE REGION,
SEMICONDISIOR INTERRATED CIRCUIT AND , the specification	
	ERFOF national Application No and was amended (if applicable) on
 '	
I hereby state that I have reviewed and understand the contents amended by any amendment referred to above. I do not know and	do not believe that the same was ever known or used by others
in the United States of America before my or our invention ther	
country before my or our invention thereof or more than one ye	
invention was not in public use or on sale in the United States of	
I understand that I have a duty of candor and good faith toward to disclose information which is material to patentability as defined in	
·	
I hereby claim foreign priority benefits under Title 35, United State	
patent or inventor's certificate, or §365(a) of any PCT internation the United States of America, listed below and have also idea	
certificate disclosing subject matter in common with the above-id	
application on which priority is claimed:	continued specification and having a thing date before that of the
	Priority Claimed Under 35 USC §119
Country App. No. Date of Filing P2001-128187 April 25, 2001	YesXNo
I hereby claim the benefit under Title 35, United States Code, § POT international application designating the United States of A claim of the present application is not disclosed in the prior United by the first paragraph of Title 35, United States Code §112, I adpute the prior application and the national or PCT international filing date of Application No. Special Potential States Code (Section 2018) Application No. Filing Date	America, listed below and, insofar as the subject matter of each d States or PCT international application in the manner provided knowledge the duty to disclose information which is material to s § 1.56, which became available between the filing date of the
Lifurther declare that all statements made herein of my own know belief are believed to be true; and further that these statement we like so made are punishable by fine or imprisonment, or both, unsuch willful false statements may jeopardize the validity of the appropriate the statements.	re made with the knowledge that willful false statements and the der Section 1001 of Title 18 of the United States Code, and that
I hereby authorize the U.S. attorneys named herein to accept and to be taken in the Patent and Trademark Office regarding this appl and the undersigned. In the event of a change in the persons from will be notified by the undersigned.	ication, without direct communication between the U.S. attorney
POWER OF ATTORNEY: The following attorneys are hereby app the Patent and Trademark Office connected therewith: Anthony B 29,105; Stephen M. Schaetzel -31,418; Larry A. Roberts - 31,871; L. Greene-32,467; Mary Anthony Merchant - 39,771; Brenda Oz Green - 41,801; John K. McDonald - 42,860; Suzanne Seavello S Chan - 44,070; John M. Briski - 44,562; S. Craig Hemenway - 4 Cheryl L. Huseman - 45,392; Shelby B. Grier - 45,785; Vaibh Bennett-Paris - P47,226	Askew - 24,154; Roger T. Frost - 22,176; Robert E. Richards - 3, James Dean Johnson - 31,771; Leona G. Young - 37,266; Jamie taki Holmes - 40,339; Kimberly J. Prior - 41,483; Theodore M. Shope - 37,933; Sima Singadia Kulkarni - 43,732; Christopher J. 14,759; Paul E. Knowlton - 44,842; Charles E. Peeler - 45,004;
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Inventor's signature Maketo Yamamoto	Date: October 22,2001

[[]X] Additional inventors are being named on separately numbered sheets attached hereto.

Attorney Docket No.: 44471-265522 (13700)

Title: Lateral Transistor Having Graded Base Region, Semiconductor Integrated Page 2 Circuit And Fabrication Method Thereof

Page 2

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Full name of third joint inventor, if any:
Citizenship:
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Inventor's signature Date:

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